



#### High Speed 1:2 Mux/DeMux

#### Description

The DIODES PSMUX136 is a 2-to-1 differential channel multiplexer/demultiplexer switch. The PSMUX136 can pass high speed signals with a bandwidth of 5.5GHz to provide excellent signal integrity and the eye diagram opening.

#### Application(s)

- Smart Phones
- Tablets
- NBs
- PCs

# **Block Diagram**



#### **Features**

- Differential Bi-Directional 2:1 Mux/DeMux
- Wide Input Voltage Range: 0V to 3.6V
- High Performance Switch Characteristics:
  - Bandwidth (-3dB): 5.5GHz (A Port); 5.3GHz (B Port)
  - $R_{ON}$  (Typical): 4.6 $\Omega$  (A Port); 5.7 $\Omega$  (B Port)
  - C<sub>ON</sub> (Typical): 1.5pF @ 240MHz
- Low Propagation Delay, 0.1ns Typical
- Low Off-Isolation: -34dB @ 240MHz
- Low Crosstalk: -37dB @ 240MHz,
- Low Power Consumption: 35µA Typical
- Power-Off Protection for Minimizing Current Leakage in Power Down Mode
- Wide Supply Voltage: 1.8V to 5.5V
- Support 1.8V Logic on Control Pins
- Wide Temperature Range: -40°C to 125°C .
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3) •
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/guality/product-definitions/

- Packaging (Pb-free & Green):
  - 10-contact, UQFN (ZUA), 1.5x2mm, 0.5mm(H), 0.6mm pitch

#### Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.





## **Pin Configuration**



## **Pin Description**

Pin#	Pin Name	Signal Type	Description	
8,	COM1,	L/O	Signal I/O. Common Dont	
7	COM2	1/0	Signal 1/O, Common Port	
3,	B1,	L/O	Signal I/O. P. Dagt Changel	
4	B2	1/0	Signal 1/O, B Port Channel	
1,	A1,	L/O	Grand L/O. A. Dort Channel	
2	A2	1/0	Signal 1/0, A Port Channel	
9	SEL	Ι	Operation mode Select (when SEL = L: COM $\rightarrow$ A Port, when SEL = H: COM $\rightarrow$ B Port)	
10	V <sub>DD</sub>	PWR	Positive Supply Voltage	
5	GND	PWR	Power ground	
6	EN	Ι	$\overline{\text{EN}}$ = 1, Chip is Power Down. $\overline{\text{EN}}$ = 0, Chip is Enabled. Please see Truth Table.	

#### **Truth Table**

Function	SEL	ĒN
COM to A Port	L	L
COM to B Port	Н	L
All Switches Hi-Z	Х	Н





## **Typical Application Diagram**







## **Maximum Ratings**

Above which useful life may be impaired. For user guidelines, not tested.)						
Storage Temperature	Note: Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rat- ing only and functional operation of the device at these or any other conditions above those indicated in the operational sec- tions of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.					

## **Recommended Operating Conditions**

Symbol	Description	Test Conditions	Min.	Тур.	Max.	Units
V <sub>DD</sub>	Power Supply		1.8	3.3	5.5	V
V <sub>I/O</sub>	Analog Voltage Range		0		3.6	V
VI	Voltage Range for Control Pins		0		5.5	V
T		$\rm V_{IO}$ = 0V, SEL = GND or $\rm V_{DD}$ , chip enabled		35	55	A
I <sub>DD</sub>	Current Consumption in Normal Operation	$V_{IO} = 0V$ , SEL = GND or $V_{DD}$ , chip enabled, $T_A = -40^{\circ}C$ to $125^{\circ}C$			75	μΑ
T		$V_{IO} = 0V$ , SEL = GND or $V_{DD}$ , $\overline{EN}$ = High		1	2	
I <sub>DDQ</sub>	Chip Disabled Current Consumption	$V_{IO}$ = 0V, SEL = GND or $V_{DD}$ , $\overline{EN}$ = High , $T_A$ = -40°C to 125°C			10	μΑ
T <sub>A</sub>	Operating Temperature Range		-40		125	°C

## DC Electrical Characteristics for Switching over Operating Range

$T_A = -40^{\circ}C$ to 125°C, Typical values are at $V_{DD} = 3.3V$ , $T_A = 25^{\circ}C$ , $\overline{EN} = 0V$ (unless otherwise noted)								
Parameter	Description	Test Conditions	Min.	Тур.	Max.	Units		
Control Pins	Control Pins – EN/SEL							
V <sub>IH</sub> - cntrl signals	Input HIGH Voltage for SEL and $\overline{\text{EN}}$	$V_{DD} = 1.8-5.5 V$	1.3			V		
V <sub>IL</sub> - cntrl signals	Input LOW Voltage for SEL and $\overline{EN}$	$V_{DD} = 1.8-5.5 V$			0.6	V		
I <sub>IH</sub>	Input HIGH Current for SEL and $\overline{EN}$	$V_{I} = 5.5 V$	-1		1	μΑ		
I <sub>IL</sub>	Input LOW Current for SEL and $\overline{EN}$	$V_{I} = 0V$	-1		1	μA		





Parameter	Description	Test Conditions		Min.	Тур.	Max.	Units
B Port Switch	l			<u></u>			
		$V_{DD} = 2.7 V$	$V_{I/O} = 1.65V, I_{ON} = -8mA$		5.7	9	
		$V_{DD} = 1.8V$	$V_{I/O} = 1.65V, I_{ON} = -8mA$		5.7	9.5	
R <sub>ON</sub>	ON-state Resistance	$V_{DD} = 2.7 V$	$V_{I/O} = 1.65$ V, $I_{ON} = -8$ mA, $T_A = -40^{\circ}$ C to $125^{\circ}$ C			13	Ω
		$V_{DD} = 1.8V$	$V_{I/O} = 1.65$ V, $I_{ON} = -8$ mA, $T_A = -40^{\circ}$ C to $125^{\circ}$ C			13	
$\Delta R_{ON}$	ON-state Resistance match between + and - paths	$V_{DD} = 1.8V$	$V_{I/O} = 1.65V$ , $I_{ON} = -8mA$		0.1		Ω
R <sub>ON(FLAT)</sub>	ON-state Resistance Flatness	$V_{DD} = 1.8V$	$V_{I/O} = 1.65V$ to 3.45V, $I_{ON} = -8mA$		1		Ω
			Switch OFF, $V_{B Port} = 1.65V$ to 3.45V, $V_{COM Port} = 0V$	-2		2	
I <sub>OZ</sub>	OFF Leakage Current	V <sub>DD</sub> = 4.8V	Switch OFF, $V_{B Port} = 1.65V$ to 3.45V, $V_{COM Port} = 0V$ , $T_A = -40^{\circ}C$ to $125^{\circ}C$	-10		10	μΑ
I <sub>OFF</sub>	Power-off Leakage Current	$V_{DD} = 0V$	Switch ON or OFF, V <sub>B Port</sub> = 1.65V to 3.45V, V <sub>COM Port</sub> = NC	-10		10	- μΑ
			Switch ON or OFF, $V_{B Port} =$ 1.65V to 3.45V, $V_{COM Port} =$ NC, $T_A = -40^{\circ}$ C to 125°C	-10		10	
	ON Leakage Current	V <sub>DD</sub> = 4.8V	Switch ON, $V_{B Port} = 1.65V$ to 3.45V, $V_{COM Port} = NC$	-2		2	- μΑ
T			Switch ON, $V_{B Port} = 1.65V$ to 3.45V, $V_{COM Port} = NC$ , $T_A = -40^{\circ}C$ to $125^{\circ}C$	-10		10	
I <sub>ON</sub>		V <sub>DD</sub> = 1.8V	Switch ON, $V_{B Port} = 1.65V$ to 3.45V, $V_{COM Port} = NC$	-2		2	
			Switch ON, $V_{B Port} = 1.65V$ to 3.45V, $V_{COM Port} = NC$ , $T_A = -40^{\circ}C$ to $125^{\circ}C$	-10		10	
A Port Switch	1		1			1	1
			$V_{I/O} = 0.4V, I_{ON} = -8mA$		4.6	7.5	-
R <sub>ON</sub>	ON-state Resistance	V <sub>DD</sub> = 1.8V	$V_{I/O} = 0.4V, I_{ON} = -8mA,$ $T_A = -40^{o}C \text{ to } 125^{o}C$			12	Ω
ΔR <sub>ON</sub>	ON-state Resistance match between + and - paths	$V_{DD} = 1.8V$	$V_{I/O} = 0.4$ V, $I_{ON} = -8$ mA		0.1		Ω
R <sub>ON(FLAT)</sub>	ON-state Resistance Flatness	$V_{DD} = 1.8V$	$V_{I/O} = 0V$ or 0.4V, $I_{ON} = -8mA$		0.2		Ω





Parameter	Description	Test Condi	tions	Min.	Тур.	Max.	Units
			Switch OFF, $V_{A Port} = 0V$ to 3.6V, $V_{COM Port} = 0V$	-2		2	
I <sub>OZ</sub>	OFF Leakage Current	V <sub>DD</sub> = 4.8V	Switch OFF, $V_{A Port} = 0V$ to 3.6V, $V_{COM Port} = 0V$ , $T_A = -40^{\circ}C$ to $125^{\circ}C$	-10		10	μΑ
			Switch ON or OFF, V <sub>A Port</sub> = 0V to 3.6V, V <sub>COM Port</sub> = NC	-10		10	
I <sub>OFF</sub>	Power-off Leakage Current	$V_{DD} = 0V$	Switch ON or OFF, $V_{A Port} =$ 0V to 3.6V, $V_{COM Port} = NC$ , $T_A = -40^{\circ}C$ to $125^{\circ}C$	-50		50	μΑ
I <sub>ON</sub>	ON Leakage Current	V <sub>DD</sub> = 4.8V	Switch ON, $V_{A Port} = 0V$ to 3.6V, $V_{COM Port} = NC$	-2		2	- μΑ
			Switch ON, $V_{A Port} = 0V$ to 3.6V, $V_{COM Port} = NC$ , $T_A = -40^{\circ}C$ to $125^{\circ}C$	-10		10	
		V <sub>DD</sub> = 1.8V	Switch ON, $V_{A Port} = 0V$ to 3.6V, $V_{COM Port} = NC$	-2		2	
			Switch ON, $V_{A Port} = 0V$ to 3.6V, $V_{COM Port} = NC$ , $T_A = -40^{\circ}C$ to $125^{\circ}C$	-10		10	

# **Dynamic Electrical Characteristics**

$T_A = -40^{\circ}C$ to 125°C, Typical values are at $V_{DD} = 3.3V$ , $T_A = 25^{\circ}C$ , (unless otherwise noted)								
Parameter	Description	Test Condi	Test Conditions		Тур.	Max.	Units	
C <sub>ON(B Port)</sub>	B Port path ON Capacitance	Switch ON	$V_{DD} = 3.3V$ , $V_{I/O} = 0$ or 3.3V, f = 240MHz		1.5	2	pF	
C <sub>ON(A Port)</sub>	A Port path ON Capacitance	Switch ON	$V_{DD} = 3.3V, V_{I/O} = 0 \text{ or } 3.3V, f = 240MHz$		1.5	2	pF	
C <sub>OFF(B Port)</sub>	B Port path OFF Capacitance	Switch OFF	$V_{DD} = 3.3V$ , $V_{I/O} = 0$ or 3.3V, f = 240MHz		1.5	2	pF	
C <sub>OFF(A Port)</sub>	A Port path OFF Capacitance	Switch OFF	$V_{DD} = 3.3V, V_{I/O} = 0 \text{ or } 3.3V, f = 240MHz$		1.5	2	pF	
CI	Digital Input Capacitance		$V_{DD} = 3.3V, V_I = 0 \text{ or } 2V$		2.2		pF	
O <sub>IOS</sub>	OFF Isolation	Switch OFF	$R_L = 50\Omega, f = 240MHz$		-34		dB	
X <sub>TALK</sub>	Crosstalk	Switch ON	$R_L = 50\Omega, f = 240MHz$		-37		dB	
B <sub>W(B Port)</sub>	B Port path -3dB Bandwidth	Switch ON	$R_{\rm L} = 50\Omega$		5.3		GHz	
B <sub>W(A Port)</sub>	A Port path -3dB Bandwidth	Switch ON	$R_{\rm L} = 50\Omega$		5.5		GHz	





# Switching Characteristics<sup>(1)</sup>

Parameter	Description	Test Conditions	Min.	Тур.	Max.	Units
t <sub>PZH</sub> , t <sub>PZL</sub>	Line Enable Time (SEL to Output)				600	ns
t <sub>PHZ</sub> , t <sub>PLZ</sub>	Line Disable Time	See Test Circuit for Electrical Characteristics		50		ns
t <sub>Pd</sub>	Propagation Delay			100		ps
t <sub>b-b</sub>	Bit-to-bit Skew Within the Same Differential Pair $^{(1)}$			8	20	ps
T <sub>on</sub>	Device Enable Time			100		μs
T <sub>off</sub>	Device Disable Time			50		ns

Note:

1. Guaranteed by design.







Figure 1. Differential Insertion Loss Setup



Figure 3. Crosstalk Setup



Figure 5. Skew Test







**Figure 4. Propagation Delay** 





#### **Switching Waveforms**



Figure 6. Voltage Waveforms Enable and Disable Times



Figure 7. Test Circuit for Propagation Delay

### **Part Marking**







#### **Packaging Mechanical**

10-UQFN (ZUA)



17-0002

For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

#### **Ordering Information**

Ordering Code	Package Code	Package Description	Pin 1 Orientation	
PSMUX136ZUAEX	ZUA	10-Pin, 1.5mmx2.0mm (UQFN)	Top Left Corner	
PSMUX136ZUAEX-7R	ZUA	10-Pin, 1.5mmx2.0mm (UQFN)	Bottom Left Corner	

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony 2. 3.
- compounds. 4. E = Pb-free and Green
- 5. X suffix = Tape/Reel
- 6. For packaging detail, go to our website at: https://www.diodes.com/assets/MediaList-Attachments/Diodes-Package-Information.pdf

PSMUX136





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